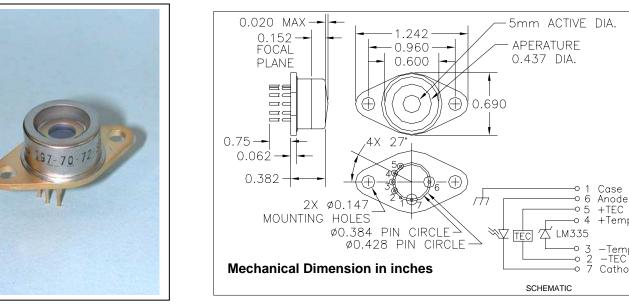


Cooled Large Area Blue Silicon Avalanche Photodiode SD 197-70-74-591



FEATURES

- Low noise
- Small size
- High Speed
- Low cost
- The SD 197-70-74-591 is a cooled large area silicon

avalanche photodiode (APD) that provides high gain and low noise, in a hermetic TO-66 package.

APPLICATIONS

- Military
- Industrial
- Medical

SYMBOL	PARAMETER	MIN	MAX	UNITS
М	Gain		350	
T _{STG}	Storage Temperature	-55	+70	C
To	Operating Temperature	+1	+40	C
Ts	Soldering Temperature*		+240	C
V _{TEC}	TEC voltage		1.5	V
I _{TEC}	TEC Current		2.0	A
Р	APD Die Power Diss.		0.2	W

ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

DESCRIPTION

SPECTRAL RESPONSE M = 300

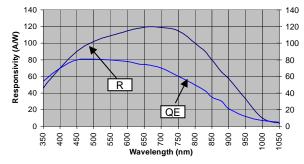
Case GND

+Temp Sensor

-Temp Sensor -TEC

Cathode

+TEC



* 1/16 inch from case for 3 seconds max.

ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _D	Dark Current			10	25	nA
CJ	Junction Capacitance	f = 1 MHz		25		pF
I _N	Noise Current Spectral Density	f = 100 kHz		0.8	1.5	pA/√Hz
λ range	Spectral Application Range	Spot Scan	350		1050	nm
R	Responsivity	λ = 500nm, V _R = 0 V		35		A/W
Vop	Operating voltage		1700		2000	V
t _r	Response Time**	RL = 50 Ω , λ = 675nm		10	15	nS
I _{QTEC}	TEC Quiescent Current	Case Temp = 35 °C		0.85		A

**Response time of 10% to 90% is specified at 830nm wavelength light.

All specifications are with the APD internally cooled to 0°C and a gain of 300.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

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